

# IRG4RC10SD

## **IRG4RC10SD Information**



## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## **IRG4RC10SD Specifications**

Manufacturer Part Number	IRG4RC10SD
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-252-3, DPak (2 Leads + Tab), SC-63
Series	-
IGBT Type	-
Voltage - Collector Emitter Breakdown (Max)	600V
Current - Collector (Ic) (Max)	14A
Current - Collector Pulsed (Icm)	18A
Vce(on) (Max) @ Vge, Ic	1.8V @ 15V, 8A
Power - Max	38W
Switching Energy	310µJ (on), 3.28mJ (off)
Input Type	Standard
Gate Charge	15nC
Td (on/off) @ 25°C	76ns/815ns
Test Condition	480V, 8A, 100 Ohm, 15V
Reverse Recovery Time (trr)	28ns
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device Package	D-Pak
	Report errors?

#### **IRG4RC10SD Guarantees**



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

### **IRG4RC10SD** Payment Methods



## **IRG4RC10SD Shipping Methods**



If you have any question about IRG4RC10SD, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com